

# **SB07W03P**

Schottky Barrier Diode (Twin Type - Cathode Common)

# 30V, 700mA Rectifier

## **Applications**

- $\cdot \ General \ rectifier.$
- · High frequency rectification (switching regulators, converters, choppers).

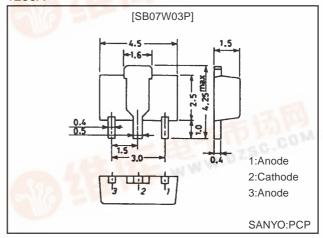
### **Features**

- · Low forward voltage ( $V_F$  max=0.55V).
- · Fast reverse recovery time (trr max=10ns).
- · Low switching noise.
- Low leakage current and high reliability due to highly reliable planar structure.

### **Package Dimensions**

unit:mm

1239A



### **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C (Value per element)

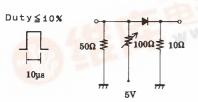
| Parameter                                 | Symbol           | Conditions              | Ratings     | Unit |  |
|---|------------------|-------------------------|-------------|------|--|
| Repetitive Peak Reverse Voltage           | VRRM             |                         | 30          | V    |  |
| Non-repetitive Peak Reverse Surge Voltage | VRSM             |                         | 35          | V    |  |
| Average Output Current                    | Io               |                         | 700         | mA   |  |
| Surge Forward Current                     | I <sub>FSM</sub> | 50Hz sine wave, 1 cycle | 5           | Α    |  |
| Junction Temperature                      | Tj               | A STATE OF THE STATE OF | -55 to +125 | °C   |  |
| Storage Temperature                       | Tstg             | 10. 7 4 - 4             | -55 to +125 | °C   |  |

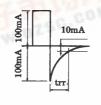
#### **Electrical Characteristics at Ta = 25°C (Value per element)**

| Parameter                 | Symbol         | Conditions   | Ratings |     |      | Unit  |
|---------------------------|----------------|--|---------|-----|------|-------|
|                           |                |  | min     | typ | max  | Offic |
| Reverse Voltage           | V <sub>R</sub> | I <sub>R</sub> =300μA  | 30      |     |      | V     |
| Forward Voltage           | ٧F             | I <sub>F</sub> =700mA  |         |     | 0.55 | V     |
| Reverse Current           | IR             | V <sub>R</sub> =15V  |         |     | 50   | μΑ    |
| Interterminal Capacitance | С              | V <sub>R</sub> =10V, f=1MHz  |         | 28  |      | pF    |
| Reverse Recovery Time     | trr            | I <sub>F</sub> =I <sub>R</sub> =100mA, See specified Test Circuit. |         | -11 | 10   | ns    |
| Thermal Resistance        | Rthj-a(1)      |  |         | 300 | 20   | °C/W  |
|                           | Rthj-a(2)      | Mounted on 250mm <sup>2</sup> ×0.8mm ceramic board                 | ALW.    | 110 |      | °C/W  |

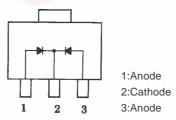
· Marking:SF

#### trr Test Circuit

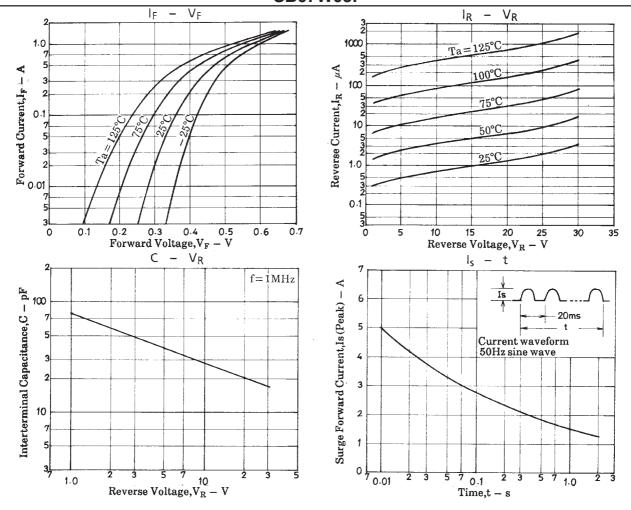




#### **Electrical Connection**



### **SB07W03P**



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